EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	96	("4965710" "5422593" "5245523" "5341003" "5847554" "5999421" "5210475" "5258957" "5293338" "5444728" "5461713" "5495155" "5589753" "5706236" "6118638" "6233125" "4267516" "4419660" "4777579" "4783690" "4907116" "4929882" "5022003" "5177586" "5233558" "5241213" "5327379" "5369308" "5475637" "5548146" "5604697" "5747849" "5777927" "5966341" "6054845" "6153980" "6180966" "6211757" "6219262" "6211757" "6219262" "6233181" "3631258" "3825777" "4255063" "4258338" "4258276" "4259716" "4262275" "4271449"). pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L16	591	(power near3 semiconductor) and comparator and fet and load	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L17	147	(power near3 semiconductor) and comparator and fet and load and (high near3 side)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L18	133	(power near3 semiconductor) and comparator and fet and load and (high near3 side) and diode	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22

L19	86	(power near3 semiconductor) and comparator and fet and load and (high near3 side) and diode and (current near3 supply)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L20	0	L19 and 324/765.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L31	215	(power near3 semiconductor) and main and sense and control$4 and load and (feedback near3 circuit) and comparator	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L32	0	L31 and 323/312.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L33	45	L31 and "323"/$.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L34	170	L31 not L33	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L35	2	("5018041").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/02/13 09:22
L36	2	("5815027").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/02/13 09:22

L38	927	(mosfet and comparator and feedback) and "327"/$.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L39	118	L38 and main and sense	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L46	255	"327"/$.ccls. and sense and main and comparator and (current near3 supply) and feedback	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L47	93	L46 and (voltage near5 fall$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L49	6	"327"/$.ccls. and (sense near3 (fet or cell)) and (main near3 (fet or cell)) and comparator and feedback	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L57	866	361/92.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L58	0	L57 and (sens$3 near3 (transistor or fet or cell)) and (main$3 near3 (transistor or fet or cell)) and comparator	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L59	2	L57 and (sens$3 near3 (transistor or fet or cell)) and (main$3 near3 (transistor or fet or cell))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22

L60	38	"361"/$.ccls. and (sens $3 near3 (transistor or fet or cell)) and (main$3 near3 (transistor or fet or cell)) and comparator	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L61	988	(monitor$3 or compar$3 or detect$3 or measur $3) near4 undervoltage	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L62	35	L61 and (sens$3 near3 (cell or transistor or fet)) and ((main or power) near3 (cell or transistor or fet))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L63	2	"6624994".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L65	4972	"361"/$.ccls. and ((below or under) near4 predetermined)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L66	1654	"361"/$.ccls. and (voltage near8 ((below or under) near4 predetermined))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L67	0	L66 and (main near3 (cell or transitor or fet)) and (sense near3 (cell or transitor or fet)) and feedback	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L68	0	L66 and (main near3 (cell or transitor or fet)) and (sense near3 (cell or transitor or fet))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22

L69	5	L66 and (main near3 (cell or transistor or fet)) and (sense near3 (cell or transistor or fet))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L70	35	"361"/93.1.ccls. and (voltage near8 ((below or under) near4 predetermined))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L71	2069	((measur$4 or determin $4 or detect$4 or sens $4) near8 ((voltage or current) near4 (transistor or fet or cell))) same ((below or low$3 or under or down) near4 (predetermin$3 or target$3 or desired))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L72	121	L71 and (power near3 semiconductor)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L73	5	L72 and "324"/$.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L74	7	L72 and "361"/$.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L75	153	L71 and "361"/$.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L76	195	((under$current or under $voltage) near8 protect $4).ti.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22

L77	38	L76 and "361"/$.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L78	157	L76 not L77	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L79	2	"7015745".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L82	1	"5815027".pn.	US-PGPUB; USPAT; USOCR	OR	ON	2009/02/13 09:22
L94	4	(low near3 voltage near3 (detect$4 or sens$4 or measur$4)) near8 (main near3 (cell or transistor or fet))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L95	0	(power near3 (switch$3 or fet or transistor or semiconductor)) same (mantain$3 near4 voltage near4 threshold)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L96	186	(power near3 (switch$3 or fet or transistor or semiconductor)) same (maintain$3 near4 voltage near4 threshold)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L97	43516	(power near3 (switch$3 or fet or transistor or semiconductor)) same ((low$3 or below or under or down) near3 (current or voltage))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L98	115597	(power near3 (switch$3 or fet or transistor or semiconductor)) same (measur$4 or detect$4 or determin$5 or sens$4 near6 ((low$3 or below or under or down) near3 (current or voltage)))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22

L99	4009	(power near3 (switch$3 or fet or transistor or semiconductor)) same (((measur$4 or detect$4 or determin$5 or sens $4) near6 ((low$3 or below or under or down) near3 (current or voltage)))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L100	381	L99 and "361"/$.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L101	52	L100 and ((under $current or under $voltage or (under near2 current) or (under near2 voltage) or (low near2 voltage) or (low near2 curent)) near4 protect$4)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L102	113	"361"/$.ccls. and (((increas$3 or ris$3) near4 voltage) same (voltage near8 fall$3 near8 (below or under or low$3 or down) near8 (predetermin$4 or target $4 or prescrib$3 or establish)))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L103	329	L100 not L101	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L104	960	361/93.1.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L105	41	L104 and ((under $current or under $voltage or (under near2 current) or (under near2 voltage) or (low near2 voltage) or (low near2 curent)) near4 protect$4)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22

L106	80	L104 and ((measur$4 or detect$3 or determin$3 or sens$3) near5 (under $current or under $voltage or (under near2 current) or (under near2 voltage) or (low near2 voltage) or (low near2 curent)))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L107	66	L106 not L105	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L112	125	(overvoltage and undervoltage) near8 compar$5	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L113	31	L112 and "361"/$.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L114	9	L112 and "327"/$.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L115	7	("4161700").PN. OR ("4743779").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2009/02/13 09:22
L116	604	comparator near8 (output$3 near5 (low near3 current))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L117	63	L116 and "361"/$.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L119	2	"6624994".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22

L120	1	(main adj cell) and (sense adj cell) and control and feedback and (current near3 supply) and comparator	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L121	1	(main adj cell) and (sense adj cell) and feedback and (current near3 supply) and comparator	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L122	2	(main adj cell) and (sense adj cell) and feedback and comparator	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L123	9	(main adj cell) and (sense adj cell) and comparator	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L124	9	(main adj cell) and (sense adj cell) and feedback	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L125	5	(main adj cell) and (sense adj cell) and (fall $3 near3 (below or under))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22
L126	6	("4743779" | "5018041" | "6624994").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/02/13 09:22

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